





DMT4004LPS

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | Ι _D T _C = +25°C |
|-------------------|-------------------------------|--|
| 40V | 2.5mΩ @ V _{GS} = 10V | 90A |
| | 4mΩ @ V _{GS} = 4.5V | 90A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$, yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

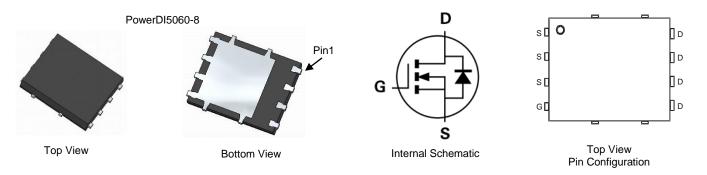
40V N-CHANNEL ENHANCEMENT MODE MOSFET POWERDI

Features

- 100% Unclamped Inductive Switching ensures more reliable and robust end application
- Low R_{DS(ON)} minimizes power losses
- Low Qg minimizes switching losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: PowerDI5060-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.097 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging | |
|---------------|---------------|---------------------|--|
| DMT4004LPS-13 | PowerDI5060-8 | 2,500 / Tape & Reel | |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.

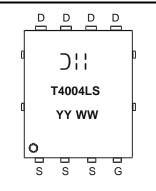
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

Notes:



) || = Manufacturer's Marking T4004LS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 16 = 2016) WW = Week (01 to 53)

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Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|---|-----------------|----------|----|
| Drain-Source Voltage | V _{DSS} | 40 | V | |
| Gate-Source Voltage | V _{GSS} | ±20 | V | |
| Continuous Drain Current (Note 5) | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | ID | 26 21 | А |
| | $T_{C} = +25^{\circ}C$ | I _D | 90 | А |
| Continuous Drain Current (Note 6) | T _C = +70°C (Note 8) | | 90 | |
| Maximum Continuous Body Diode Forward Current (Note 6) | I _S | 70 | A | |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | I _{DM} | 100 | A | |
| Avalanche Current, L=0.2mH | | I _{AS} | 33.3 | A |
| Avalanche Energy, L=0.2mH | | E _{AS} | 110 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit |
|--|------------------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | T _A = +25°C | PD | 2.6 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | | R _{0JA} | 47 | °C/W |
| Total Power Dissipation (Note 6) | T _C = +25°C | PD | 138 | W |
| Thermal Resistance, Junction to Case (Note 6) | | R _{θJC} | 0.9 | °C/W |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C |

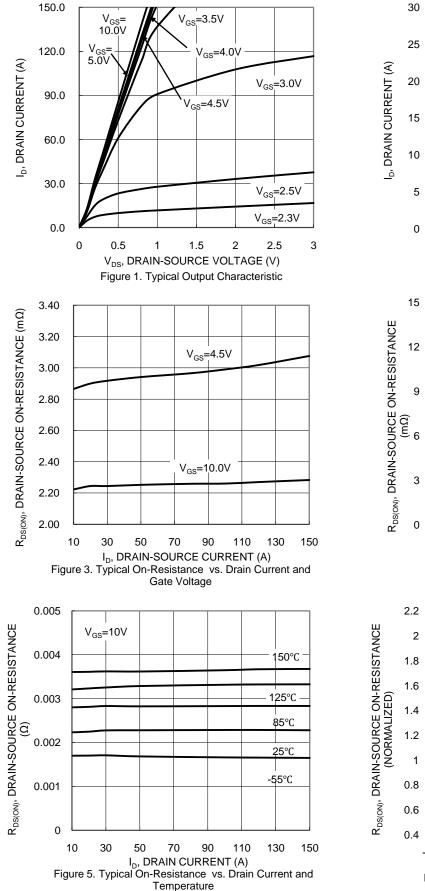
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

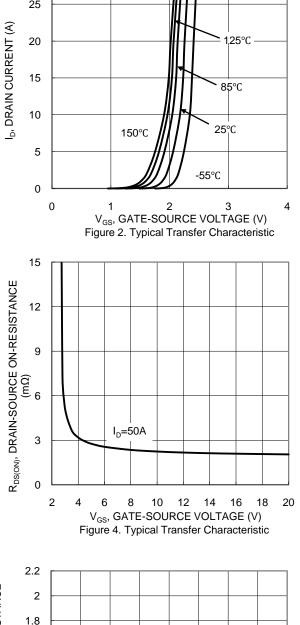
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|------|------|------|---|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 40 | — | - | V | $V_{GS} = 0V, I_D = 1mA$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | | — | 1 | μA | $V_{DS} = 32V, V_{GS} = 0V$ | |
| Gate-Source Leakage | IGSS | _ | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | · | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | — | 3 | V | $V_{DS} = V_{GS}$, $I_D = 250 \mu A$ | |
| Static Drain-Source On-Resistance | | | — | 2.5 | mΩ | $V_{GS} = 10V, I_D = 50A$ | |
| | R _{DS(ON)} | | — | 4 | mΩ | $V_{GS} = 4.5V, I_D = 50A$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.9 | 1.2 | V | $V_{GS} = 0V, I_{S} = 50A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | · | | | | | | |
| Input Capacitance | Ciss | | 4508 | — | | $V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz | |
| Output Capacitance | Coss | | 1648 | - | pF | | |
| Reverse Transfer Capacitance | Crss | | 104 | - | | | |
| Gate resistance | Rg | _ | 0.7 | — | Ω | $V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | - | 34.6 | — | nC | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 82.2 | — | | $V_{DD} = 20V, I_D = 30A$ | |
| Gate-Source Charge | Q _{gs} | _ | 9.9 | — | nC | | |
| Gate-Drain Charge | Q _{qd} | _ | 11.2 | — | | | |
| Turn-On Delay Time | t _{D(ON)} | _ | 5.9 | — | | V _{DD} = 20V, V _{GS} = 10V, | |
| Turn-On Rise Time | t _R | _ | 13.3 | — | ns | | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 25.9 | — | | $I_D = 30A, R_G = 1.6\Omega$ | |
| Turn-Off Fall Time | t _F | _ | 7.9 | — | | | |
| Body Diode Reverse Recovery Time | t _{RR} | | 48.4 | — | ns | L 500 di/dt 1000/000 | |
| Body Diode Reverse Recovery Charge | Q _{RR} | _ | 72.4 | — | nC | — I _F = 50A, di/dt = 100A/μs | |

5. Device mounted with exposed drain pad on 25mm by 25mm 2oz copper on a single- sided 1.6mm FR-4 PCB; device is measured under still air conditions Notes: b) Device mounted with exposed train pad on 25mm by 25mm 202 copper on a sill whilst operating in a steady state.
c) Thermal resistance from junction to soldering point (on the exposed drain pad).
7) Short duration pulse test used to minimize self-heating effect.
8) Guaranteed by design. Not subject to production testing.

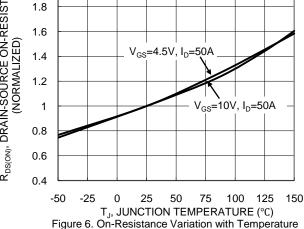


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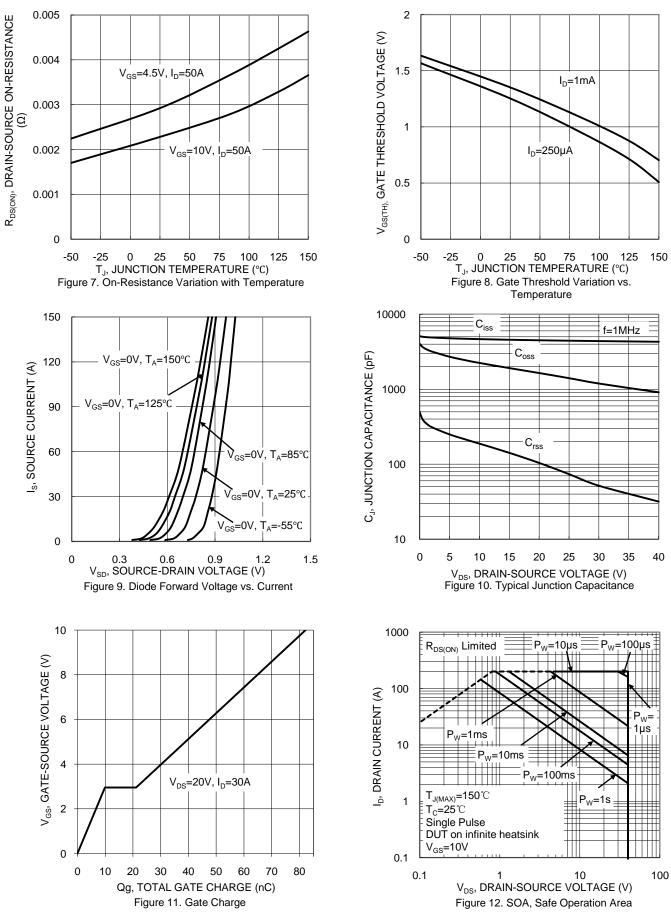
V_{DS}= 5.0V



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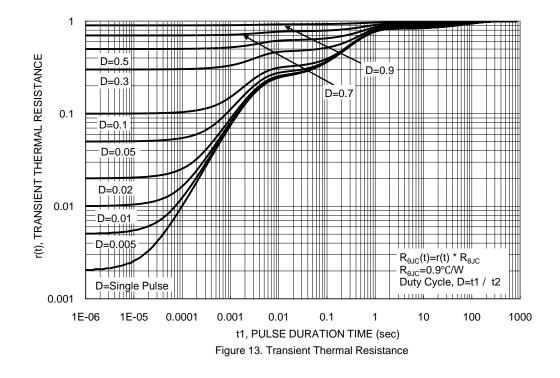
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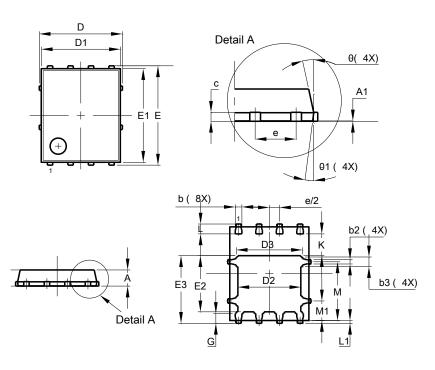
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

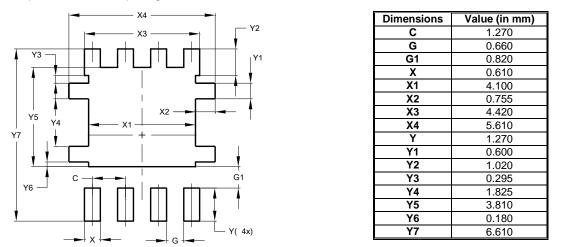


| | PowerDI5060-8 | | | | | |
|----------------------|---------------|----------|-----------------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | 0.90 | 1.10 | 1.00 | | | |
| A1 | 0.00 | 0.05 | - | | | |
| b | 0.33 | 0.51 | 0.41 | | | |
| b2 | 0.200 | 0.350 | 0.273 | | | |
| b3 | 0.40 | 0.80 | 0.60 | | | |
| c | 0.230 | 0.330 | 0.277 | | | |
| D | 5.15 BSC | | | | | |
| D1 | 4.70 | 5.10 | 4.90 | | | |
| D2 | 3.70 | 4.10 | 3.90 | | | |
| D3 | 3.90 | 4.30 | 4.10 | | | |
| Е | e | 6.15 BSC | | | | |
| E1 | 5.60 | 6.00 | 5.80 | | | |
| E2 | 3.28 | 3.68 | 3.48 | | | |
| E3 | 3.99 | 4.39 | 4.19 | | | |
| e | 1.27 BSC | | | | | |
| G | 0.51 | 0.71 | 0.61 | | | |
| K | 0.51 | - | - | | | |
| L | 0.51 | 0.71 | 0.61 | | | |
| L1 | 0.100 | 0.200 | 0.175 | | | |
| Μ | 3.235 | 4.035 | 3.635 | | | |
| M1 | 1.00 | 1.40 | 1.21 | | | |
| θ | 10º | 12º | 11 ⁰ | | | |
| θ1 | 6° | 8º | 7° | | | |
| All Dimensions in mm | | | | | | |



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



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